L Number	Hits	Search Text	DB	Time stamp
1	11665	capacitor near8 (substrate or trench or groove)	USPAT	2003/07/08 15:29
2	11433	capacitor near8 (substrate or trench or groove) and substrate	USPAT	2003/07/08 15:30
3	11433	(capacitor near8 (substrate or trench or groove)) and substrate	USPAT	2003/07/08 15:30
4	7104	(capacitor near3 (substrate or trench or groove)) and substrate	USPAT	2003/07/08 15:30
5	5709	(capacitor near3 (substrate or trench or groove)) and substrate and semiconductor	USPAT	2003/07/08 15:31
6	4725	(capacitor near3 (substrate or trench or groove)) and substrate and semiconductor and ("257" or "438")	USPAT	2003/07/08 15:32
7	2134	(capacitor near3 (trench or groove)) and substrate and semiconductor and ("257" or "438")	USPAT	2003/07/08 16:19
8	62	(back adj2 side adj2 contact) and capacitor	USPAT	2003/07/08 16:25
9	12	(back adj2 side adj2 contact) and capacitor	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 16:27
10	54	capacitor near5 (clock adj line)	USPAT	2003/07/08 16:33
11	2	capacitor near6 ("input/output" adj pad)	USPAT	2003/07/08 16:43
12	9	capacitor near6 ("input/output" adj pad)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/08 16:43